

Engineering Development Model

RF Transformer

TC1-ED11339/1

Impedance Ratio : 1

Important Note

This model has been designed, built and tested in our engineering department. Performance data represents model capability. At present it is a non-catalog model. On request, we can supply a final specification sheet, part number and price/delivery information.



Please click "Back", and then click "Contact Us" for Applications support.

CASE STYLE : AT224

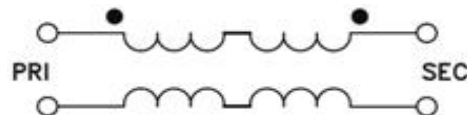
ELECTRICAL SPECIFICATIONS 75Ω @ +25°C				
Parameter	Min.	Typ.	Max.	Units
Frequency	30		1100	MHz
Insertion Loss *	3 dB Bandwidth	30 - 1100		MHz
	2 dB Bandwidth	400 - 900		MHz
	1 dB Bandwidth	530 - 550		MHz

Note:

* Insertion Loss is referenced to mid-band loss, 0.15dB typ.

MAXIMUM RATINGS	
Operating Temperature	-40°C to 85°C
Storage Temperature	-55°C to 100°C
RF Power	0.25 W
DC Current	30 mA

Configuration : G



PIN CONNECTIONS	
PRIMARY DOT	6
PRIMARY	4
SECONDARY DOT	1
SECONDARY	3
ISOLATE	2